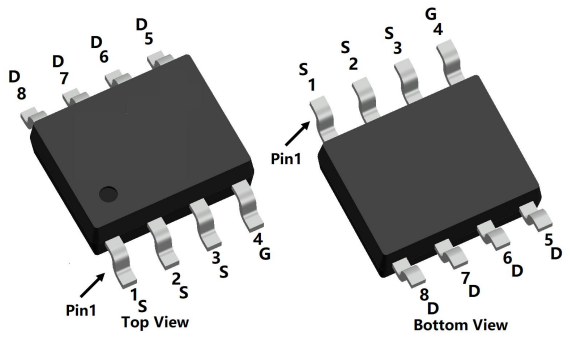
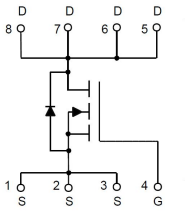
N-Channel Enhancement Mode Field Effect Transistor



SOP-8



Product Summary

- V_{DS} 150V
- I_D 5A
- $R_{DS(ON)}$(at V_{GS}=10V) ＜70mΩ
- $R_{DS(ON)}$(at V_{GS}=6V) ＜80mΩ
- 100% EAS Tested

General Description

- Split gate trench MOSFET technology
- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Moisture Sensitivity Level 3
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Switching Voltage Regulators
- DC-DC convertor

■ Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	150	V
Gate-source Voltage		V_{GS}	±20	V
Drain Current	T_A=25℃	I_D	5	A
	T_A=100℃		3	
Pulsed Drain Current [A]		I_{DM}	40	A
Avalanche energy [B]		EAS	4.4	mJ
Total Power Dissipation [C]	T_A=25℃	P_D	3.5	W
	T_A=100℃		1.4	
Junction and Storage Temperature Range		T_J ,T_{STG}	-55～+150	℃

■Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient [D]	Steady-State	$R_{\theta JA}$	30	35	℃/W

■ Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
S05G15A	F2	Q05G15A	4000	8000	64000	13“ reel

■ Electrical Characteristics (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}= 0V, I_D=250μA	150	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=150V, V_{GS}=0V	-	-	1	μA
		V_{DS}=150V, V_{GS}=0V, Tj=150℃	-	-	100	
Gate-Body Leakage Current	I_{GSS}	V_{GS}= ±20V, V_{DS}=0V	-	-	±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}= V_{GS}, I_D=250μA	2	3	4	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=5A	-	50	70	mΩ
		V_{GS}=6V, I_D=3A	-	55	80	
Diode Forward Voltage	V_{SD}	I_S=5A, V_{GS}=0V	-	0.9	1.2	V
Gate resistance	R_G	f=1MHz, Open drain	-	1.2	-	Ω
Maximum Body-Diode Continuous Current	I_S		-	-	5	A
Dynamic Parameters						
Input Capacitance	C_{iss}	V_{DS}=75V, V_{GS}=0V, f=1MHz	-	750	-	pF
Output Capacitance	C_{oss}		-	65	-	
Reverse Transfer Capacitance	C_{rss}		-	5	-	
Switching Parameters						
Total Gate Charge	Q_g	V_{GS}=10V, V_{DS}=75V, I_D=5A	-	16	-	nC
Gate-Source Charge	Q_{gs}		-	3	-	
Gate-Drain Charge	Q_{gd}		-	4	-	
Reverse Recovery Charge	Q_{rr}	I_F=5A, di/dt=100A/us	-	235	-	nC
Reverse Recovery Time	t_{rr}		-	41	-	ns
Turn-on Delay Time	$t_{D(on)}$	V_{GS}=10V, V_{DD}=75V, I_D=5A R_{GEN}=2.2Ω	-	7	-	ns
Turn-on Rise Time	t_r		-	20	-	
Turn-off Delay Time	$t_{D(off)}$		-	16	-	
Turn-off fall Time	t_f		-	14	-	

A. Repetitive rating; pulse width limited by max. junction temperature.
B. T_J=25℃, V_{DD}=150V, V_G=10V, R_G=25Ω, L=0.5mH, IAS=4.2A.
C. P_d is based on max. junction temperature, using junction-case thermal resistance.
D. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in^2 FR-4 board with 2oz. Copper, in the still air environment with T_A =25℃. The maximum allowed junction temperature of 150℃. The value in any given application depends on the user's specific board design.

■Typical Electrical and Thermal Characteristics Diagrams

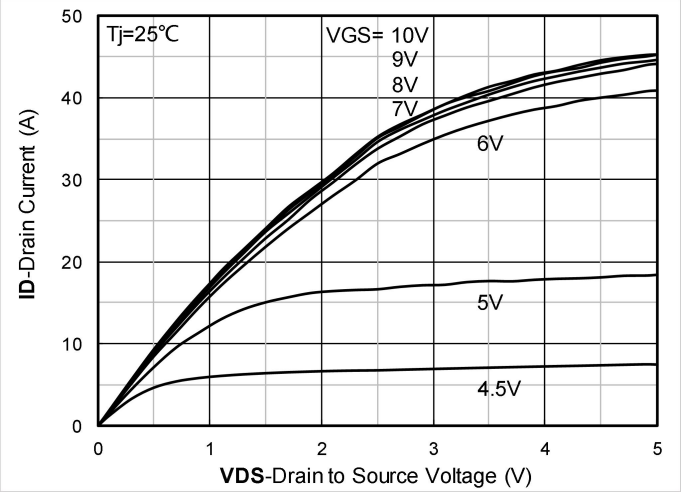


Figure 1. Output Characteristics

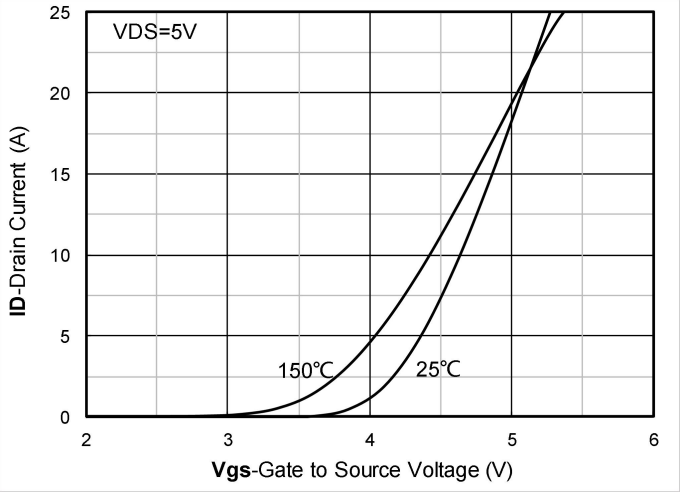


Figure 2. Transfer Characteristics

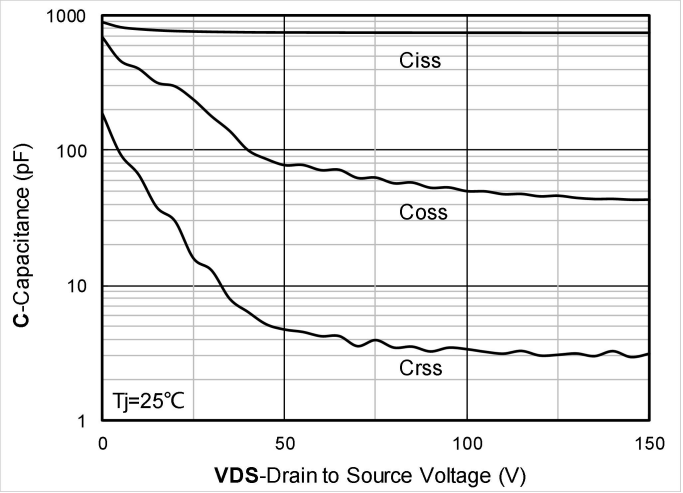


Figure 3. Capacitance Characteristics

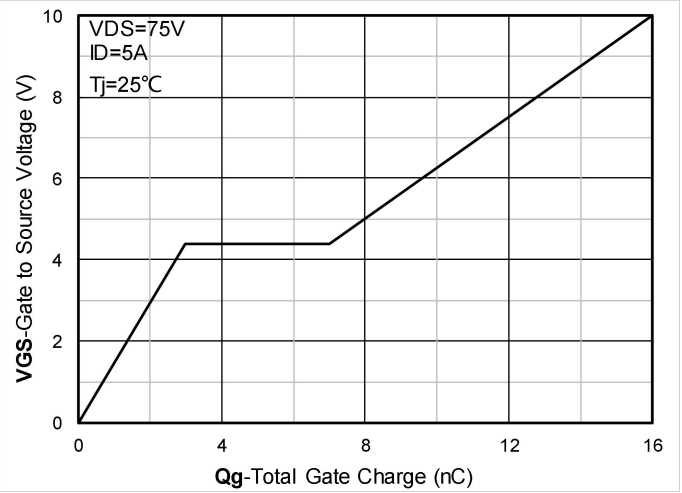


Figure 4. Gate Charge

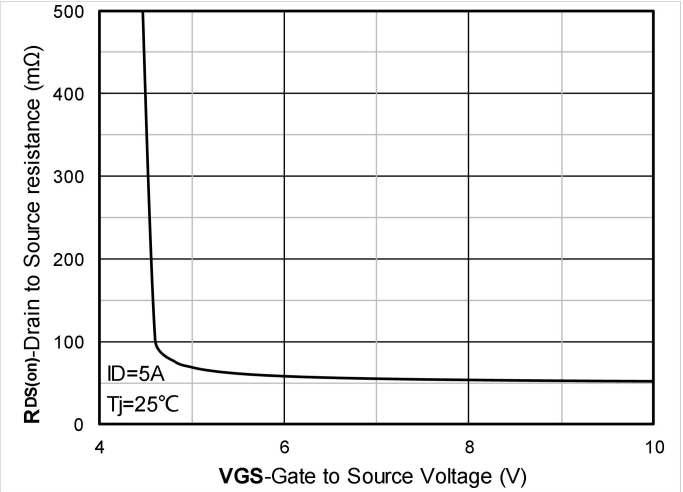


Figure 5. On-Resistance vs Gate to Source Voltage

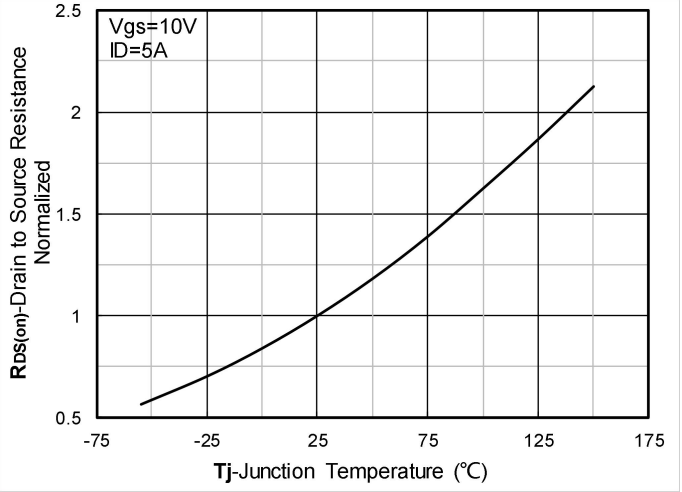


Figure 6. Normalized On-Resistance

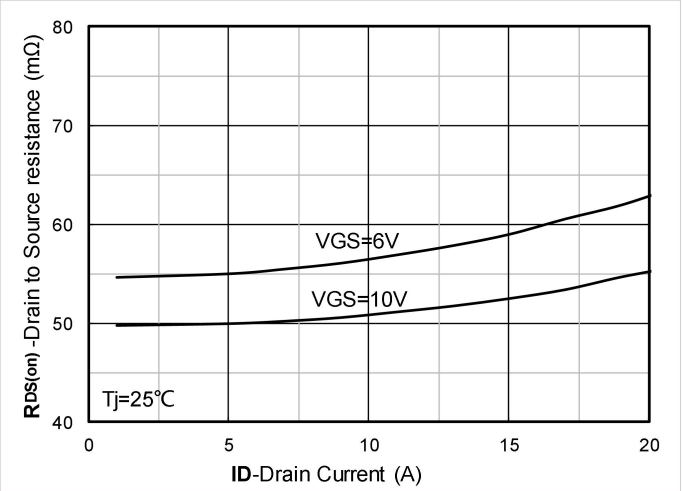


Figure 7. $R_{DS(on)}$ VS Drain Current

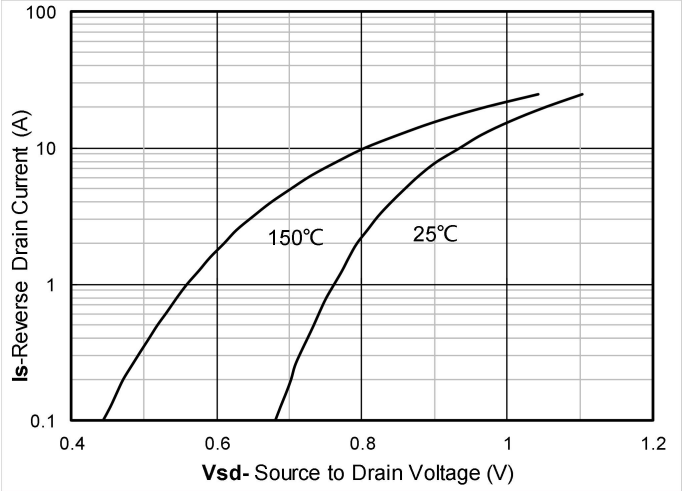


Figure 8. Forward characteristics of reverse diode

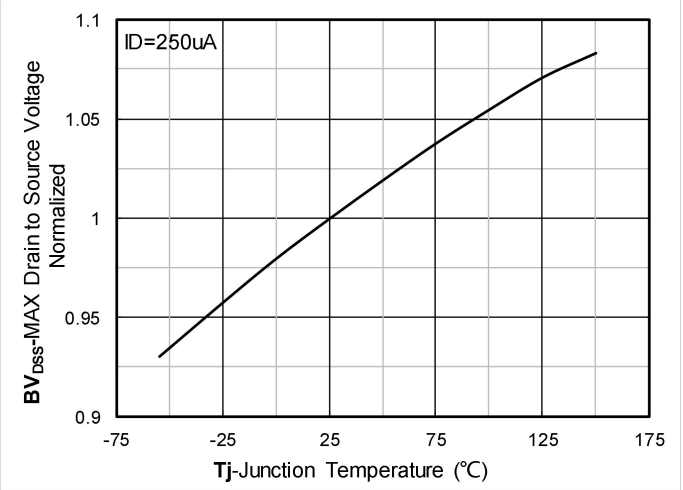


Figure 9. Normalized breakdown voltage

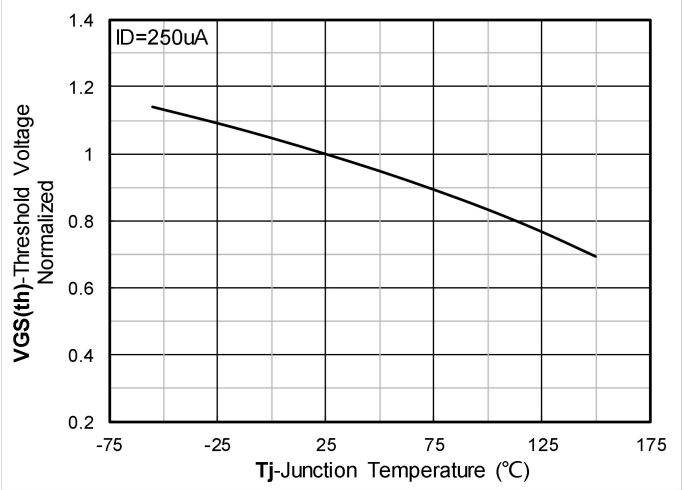


Figure 10. Normalized Threshold voltage

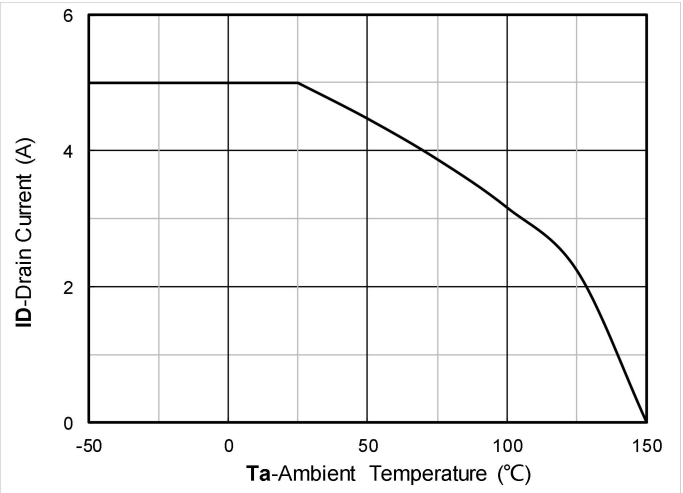


Figure 11. Current dissipation

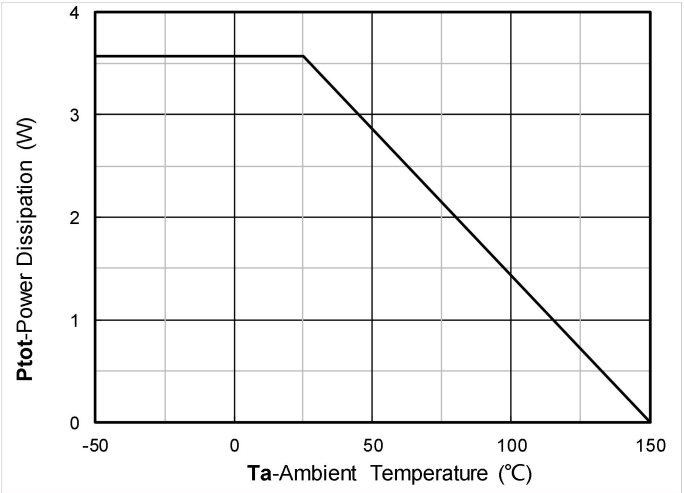


Figure 12. Power dissipation

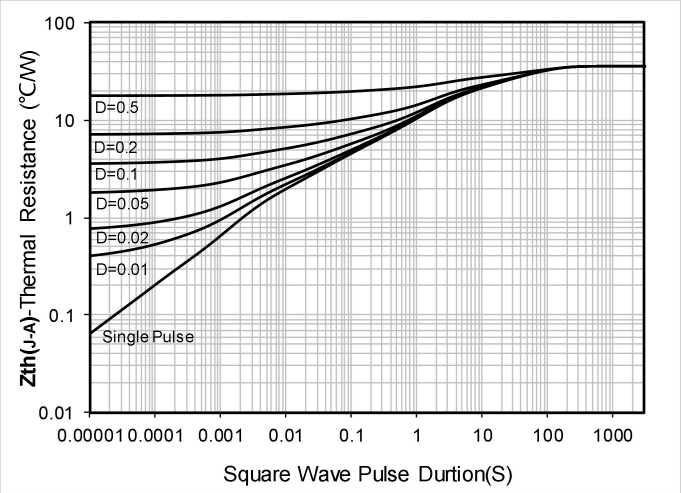


Figure 13. Maximum Transient Thermal Impedance

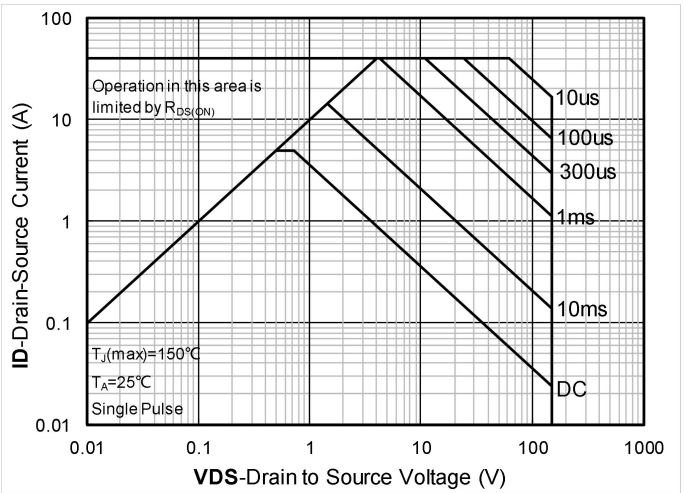
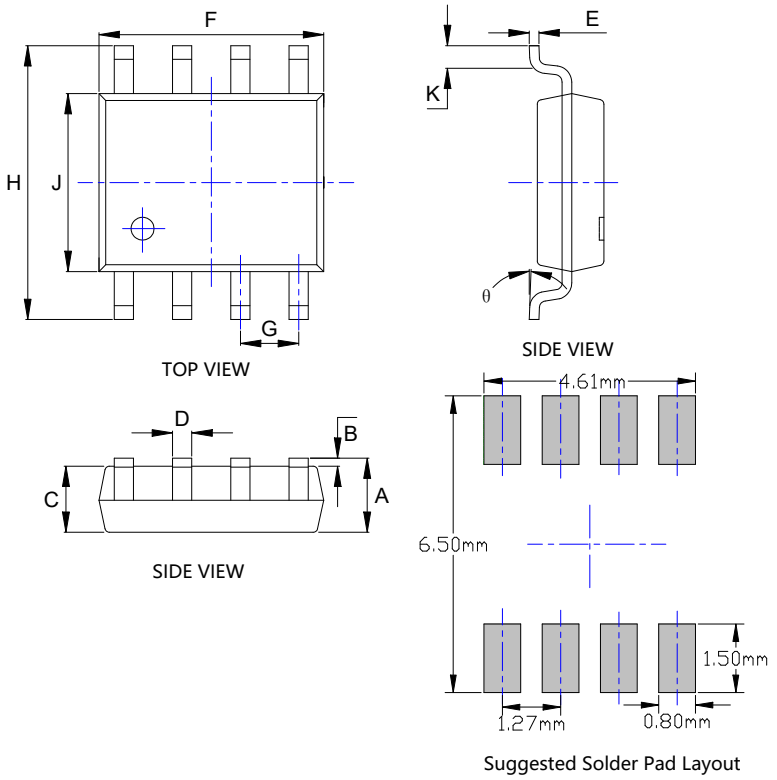


Figure 14. Safe Operation Area

■ SOP8 Package information



DIMENSIONS				
SYMBOL	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.053	0.069	1.350	1.750
B	0.004	0.010	0.100	0.250
C	0.053	0.061	1.350	1.550
D	0.013	0.020	0.330	0.510
E	0.007	0.010	0.170	0.250
F	0.189	0.197	4.800	5.000
G	0.050BSC		1.270BSC	
H	0.228	0.244	5.800	6.200
J	0.150	0.157	3.800	4.000
K	0.016	0.050	0.400	1.270
θ	0°	8°	0°	8°

Note:
1.Controlling dimension:in millimeters.
2.General tolerance:+/-0.05mm.
3.The pad layout is for reference purposes only.

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